

# HAL403 Linear Hall Effect Sensor – Engineering Translation & Design Notes

## 1. Overview

HAL403 is a compact, general-purpose linear Hall-effect sensor. Its output voltage is proportional to the magnetic flux density applied to the sensitive surface. At zero magnetic field, the output is nominally  $V_{DD}/2$ . For TO/SW packages, the presence of a north magnetic pole on the marked surface causes the output voltage to increase linearly with magnetic field strength; a south pole causes a linear decrease. For SO packages, the magnetic polarity response is reversed. The device integrates thin-film resistors to improve temperature stability and accuracy, and features low output noise, eliminating the need for external filtering. The operating temperature range is  $-40\text{ }^{\circ}\text{C}$  to  $+150\text{ }^{\circ}\text{C}$ , suitable for industrial environments.

## 2. Key Features

- Good long-term stability
- Rail-to-rail output
- Low power consumption ( $V_{DD} = 1.8\text{ V}$ ,  $I_{DD} < 1.5\text{ mA}$ )
- High sensitivity ( $V_{DD} = 3.3\text{ V}$ , typ.  $4.1\text{ mV/Gauss}$ )

## 3. Typical Applications

- Joysticks
- Motion detection
- Magnetic-axis keyboards
- Rotary encoders

## 4. Pin Definitions

Pin	Name	Description
1	VDD	Supply voltage
2	GND	Ground
3	OUT	Analog output

## 5. Electrical Characteristics (TA = 25 °C)

Supply voltage range: 1.6 V to 3.6 V (absolute max 7 V). Supply current: typ. 0.8 mA at 1.8 V, typ. 1.4 mA at 3.3 V. Output resistance: typ. 10 k $\Omega$ . Output noise (BW = 10 Hz–10 kHz): typ. 2.4 mVRMS. Bandwidth: typ. 5 kHz. Startup time: typ. 4  $\mu$ s, max 8  $\mu$ s (dvcc/dt  $\geq$  5 V/ $\mu$ s).

## 6. Magnetic Characteristics

Sensitivity at VDD = 3.3 V: min 3.6, typ. 4.1, max 4.6 mV/Gauss. Sensitivity at VDD = 1.8 V: typ. 2.2 mV/Gauss. Linear magnetic field range:  $\pm$ 390 Gs (rated),  $\pm$ 500 Gs max. Linearity error:  $\pm$ 1.5 % of full scale. Zero-field output voltage (VDD = 3.3 V): typ. 1.65 V. Zero-offset drift:  $\pm$ 0.10 %/°C.

## 7. Recommended Application Circuit

A standard decoupling configuration is recommended: place a 0.1  $\mu\text{F}$  ceramic capacitor (C1) between VDD and GND, and an optional 0.1  $\mu\text{F}$  capacitor (C2) from OUT to GND for additional noise suppression if required. Keep traces short and provide a solid ground plane for best noise performance.

## 8. Engineering Design Notes

- The ratiometric output ( $V_{\text{OUT}} \approx V_{\text{DD}}/2$  at 0 Gs) simplifies ADC interfacing when using the same reference as VDD.
- For maximum linearity, operate within the  $\pm 390$  Gs magnetic range.
- Temperature drift should be considered in precision applications; calibration may be required.
- Avoid placing strong stray magnetic fields or ferromagnetic materials near the sensor.
- Use proper ESD handling; device rating is HBM  $\pm 4$  kV.